

CBRLDSH1-40
SURFACE MOUNT
LOW PROFILE
1 AMP SILICON
SCHOTTKY BRIDGE RECTIFIER



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CBRLDSH1-40 is a full wave Schottky bridge rectifier mounted in a low profile epoxy surface mount molded case, utilizing glass passivated chips.



MARKING CODE: CLP1

APPLICATIONS:

- Solid state lighting (SSL)
- DC-DC converters
- Polarity protection

FEATURES:

- Low leakage current (16 μ A TYP @ V_{RRM})
- Low profile case (1.45mm MAX)
- Low V_F Schottky diodes (450mV TYP @ $I_F=1.0A$)

MAXIMUM RATINGS: ($T_A=25^\circ C$ unless otherwise noted)

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	40	V
DC Blocking Voltage	V_R	40	V
RMS Reverse Voltage	$V_{R(RMS)}$	28	V
Average Forward Current	I_O	1.0	A
Peak Forward Surge Current ($t_p=8.3ms$)	I_{FSM}	30	A
Operating & Storage Junction Temperature	T_J, T_{stg}	-55 to +150	$^\circ C$
Thermal Resistance	θ_{JA}	95	$^\circ C/W$

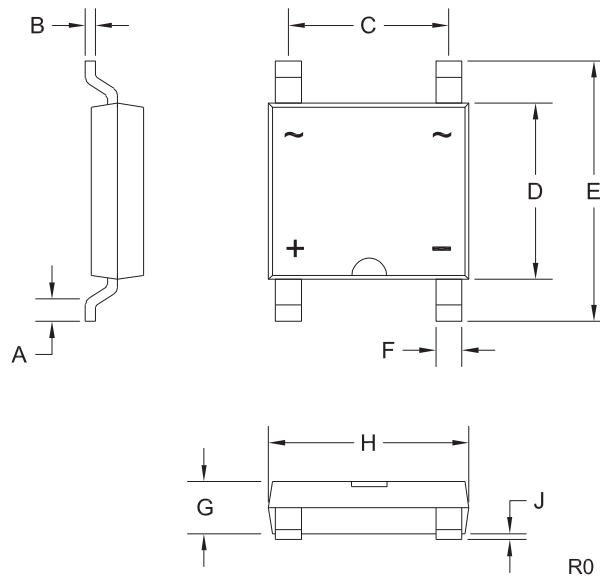
ELECTRICAL CHARACTERISTICS PER DIODE: ($T_A=25^\circ C$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_R	$V_R=40V$		16	100	μA
BV_R	$I_R=0.1mA$	40	50		V
V_F	$I_F=1.0A$		450	500	mV
C_J	$V_R=4.0V, f=1.0MHz$		110		pF

CBRLDSH1-40
 SURFACE MOUNT
 LOW PROFILE
 1 AMP SILICON
 SCHOTTKY BRIDGE RECTIFIER



LPDIP CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.019	0.028	0.50	0.70
B	0.007	0.012	0.20	0.30
C	0.153	0.162	3.90	4.10
D	0.167	0.179	4.25	4.55
E	0.248	0.264	6.30	6.70
F	0.023	0.028	0.60	0.70
G	0.045	0.058	1.15	1.45
H	0.190	0.203	4.85	5.15
J	0.002	0.006	0.05	0.15

LPDIP (REV: R0)

MARKING CODE: CLP1

R1 (17-January 2012)